



Continental Device India Pvt. Limited

An IATF 16949, ISO9001 and ISO 14001 Certified Company



NPN SILICON PLANAR EPITAXIAL TRANSISTORS

CMBT2222

CMBT2222A



SOT-23

SOT-23

Formed SMD Package
RoHS compliant

Device marking

CMBT2222 =1B

CMBT2222A =1P

ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Min/ Max	CMBT 2222	CMBT 2222A	Unit
Collector-base voltage (open emitter)	V_{CBO}	Max	60	75	V
Collector emitter voltage (open base)	V_{CEO}	Max	30	40	V
Emitter base voltage (open collector)	V_{EBO}	Max	5.0	6.0	V
Collector current (dc.)	I_C	Max	600		mA
Collector current Peak	I_{CM}	Max	800		mA
Total power dissipation up to $T_{amb} = 25^\circ\text{C}$ ¹	P_{tot}	Max	225		mW
Storage Temperature Range	T_{stg}	Min	-55	$^\circ\text{C}$	$^\circ\text{C}$
	T_{stg}	Max	150		
Junction Temperature	T_j	Max	150		
THERMAL RESISTANCE					
From junction to ambient	$R_{\theta ja}$		500		$^\circ\text{C/W}$



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ELECTRICAL CHARACTERISTICS (T_j = 25 °C Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min/Max	CMBT 2222	CMBT 2222A	Unit
Collector Emitter Breakdown Voltage	BV _{CEO}	I _C =10mA, I _B =0	Min	30	40	V
Collector Base Break down Voltage	BV _{CBO}	I _C = 10uA; I _E = 0	Min	60	75	V
Emitter Base Break down Voltage	BV _{EBO}	I _C = 0; I _E = 10uA	Min	5.0	6.0	V
Base cutoff Current	I _{BL}	V _{CE} =60V, V _{EB(off)} =3.0V	Max	--	20	nA
Emitter-Base Cutoff Current	I _{EBO}	V _{EB} =3V, I _C =0	Max	--	100	nA
Collector Cut Off Current	I _{CBO}	I _E = 0 , V _{CB} = 50 V	Max	0.01	--	µA
	I _{CBO}	I _E = 0 , V _{CB} = 60 V	Max	-	0.01	µA
	I _{CBO}	I _E = 0; V _{CB} = 50V; T _A = 125 °C	Max	10	-	µA
	I _{CBO}	I _E = 0; V _{CB} = 60V;T _A = 125 °C	Max	-	10	µA
Collector Cut Off Current	I _{CEX}	V _{EB(off)} = 3V, V _{CE} = 60V	Max	-	10	nA
Emitter-base cut-off current	I _{EBO}	I _C = 0, V _{EB} = 3V	Max	-	100	nA
Saturation Voltages ²	V _{CESat}	I _C = 150mA , I _B = 15mA	Max	400	300	mV
	V _{BESat}		Min	-	0.6	V
	V _{BESat}		Max	1.3	1.2	V
	V _{CESat}	I _C = 500mA , I _B = 50mA	Max	1.6	1.0	V
	V _{BESat}		Max	2.6	2.0	V
DC Current Gain	h _{FE}	I _C = 0.1mA; V _{CE} = 10V	Min	35		
		I _C = 1mA; V _{CE} = 10V	Min	50		
		I _C = 10 mA; V _{CE} = 10 V	Min	75		
		I _C = 10mA, V _{CE} = 10V, T _A = -55°C	Min	-	35	
		I _C = 150mA; V _{CE} = 10V ²	Min	50		
		I _C = 150mA; V _{CE} = 1V ²	Min	30		
		I _C = 500mA; V _{CE} = 10V ²	Min	40	-	
		I _C =10mA, V _{CE} =10V, T _J =125°C	Min	-	35	
Current - Gain - Bandwidth Product ³	f _T	V _{CE} = 20 V, I _C = 20 mA, f = 100 MHz	Min	250	300	MHz
Input Impedance	h _{ie}	V _{CE} = 10V, I _C = 1mA, f = 1 kHz	Min	2.0		
			Max	8.0		
		V _{CE} = 10V, I _C = 10mA, f = 1 kHz	Min	0.25		
			Max	1.25		



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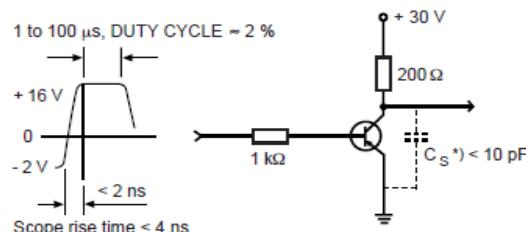


ELECTRICAL CHARACTERISTICS ($T_j = 25^\circ\text{C}$ Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min/Max	CMBT 2222	CMBT 2222A	Unit
Voltage feedback Ratio	h_{re}	$V_{CE}=10\text{ V}$, $I_C=1\text{ mA}$, $f=1\text{ kHz}$	Max	-	8.0	$\times 10^{-4}$
		$V_{CE}=10\text{ V}$, $I_C=10\text{ mA}$, $f=1\text{ kHz}$	Max	-	4.0	
Output Admittance	h_{oe}	$V_{CE}=10\text{ V}$, $I_C=1\text{ mA}$, $f=1\text{ kHz}$	Min	5.0	umhos	
		$V_{CE}=10\text{ V}$, $I_C=10\text{ mA}$, $f=1\text{ kHz}$	Max	35		
		$V_{CE}=10\text{ V}$, $I_C=10\text{ mA}$, $f=1\text{ kHz}$	Min	25		
		$V_{CE}=10\text{ V}$, $I_C=10\text{ mA}$, $f=1\text{ kHz}$	Max	200		
Collector Base Time constant	$r_b C_{CC}$	$I_E = 20\text{ mA}$, $V_{CB} = 20\text{ V}$, $f = 31.8\text{ MHz}$	Max.	150		ps
Output Capacitance at $f = 1\text{ MHz}$	C_{obo}	$I_E = 0$, $V_{CB} = 10\text{ V}$	Max	8		pF
Input Capacitance at $f = 1\text{ MHz}$	C_{ibo}	$I_C = 0$, $V_{EB} = 0.5\text{ V}$	Max	30	25	pF
Noise figure at $R_s = 1\text{ K}\Omega$	NF	$I_C = 100\mu\text{A}$, $V_{CE} = 10\text{ V}$, $R_s = 10\text{ K}\Omega$ $f = 1\text{ KHz}$	Max	--	4.0	dB
Delay Time ^{fig.1}	t_d	$V_{CC} = 30\text{ V}$, $V_{BEoff} = -0.5\text{ V}$, $I_C = 150\text{ mA}$, $I_{B1} = 15\text{ mA}$	Max	--	10	ns
Rise Time ^{fig.1}	t_r		Max	--	25	ns
Storage Time ^{fig.2}	t_s	$V_{CC} = 30\text{ V}$, $I_C = 150\text{ mA}$, $I_{B1} = I_{B2} = 15\text{ mA}$	Max	--	225	ns
Fall Time ^{fig.2}	t_f		Max	--	60	ns
Small Signal Current Gain						
Small Signal Current Gain	h_{fe}	$I_C = 1\text{ mA}$, $V_{CE} = 10\text{ V}$, $f = 1\text{ KHz}$	Min	50	--	
		$I_C = 10\text{ mA}$, $V_{CE} = 10\text{ V}$, $f = 1\text{ KHz}$	Max	300	--	
			Min	75		
			Max	375		

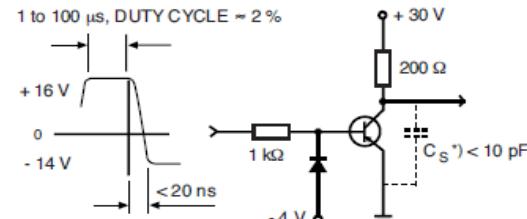
Notes:

- FR-5 = $1.0 \times 0.75 \times 0.062$ inch
- Pulse Test: pulse Width $\leq 300\text{ }\mu\text{s}$, Duty cycle $\leq 2.0\%$
- f_T is defined as the frequency at which $|h_{fe}|$ extrapolates to unity.



Total shunt capacitance of test jig, connectors and oscilloscope

Fig. 1. Turn-On Time



Total shunt capacitance of test jig, connectors and oscilloscope

Fig. 2. Turn-Off Time

Typical Characteristic curves

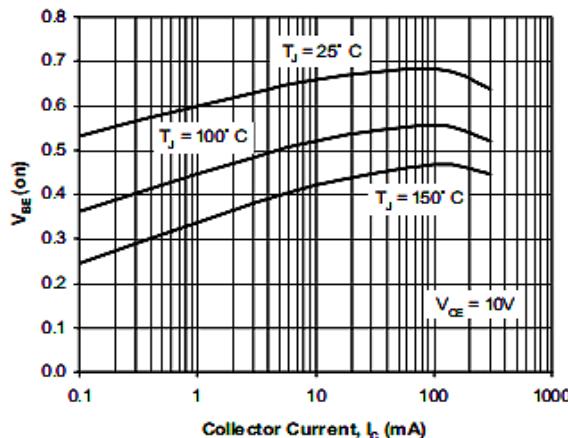
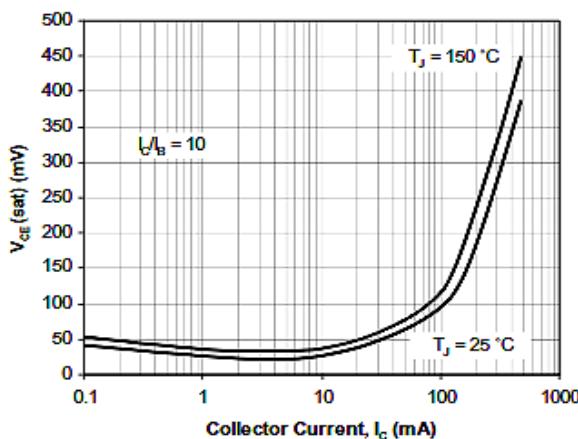
 Fig 3: Typical V_{BE} vs Collector Current

 Fig 4: Typical $V_{CE(sat)}$ vs Collector Current


Fig 5: Typical Capacitance vs Reverse Voltage

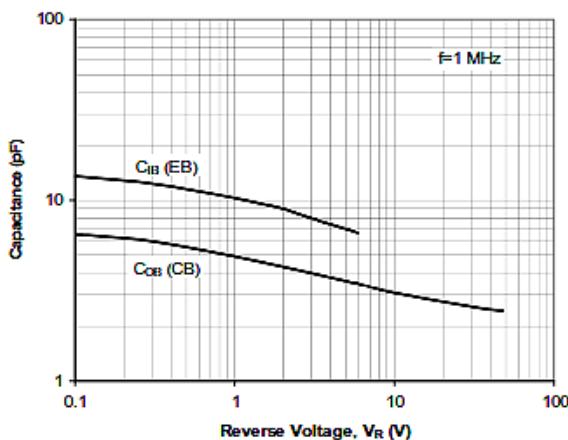


Fig 6: Turn On and Turn Off Times vs Collector Current

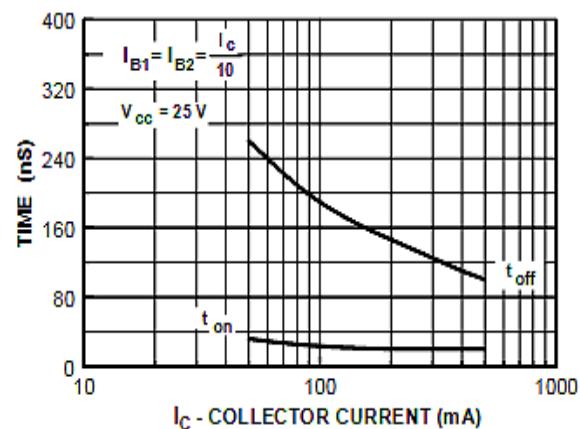
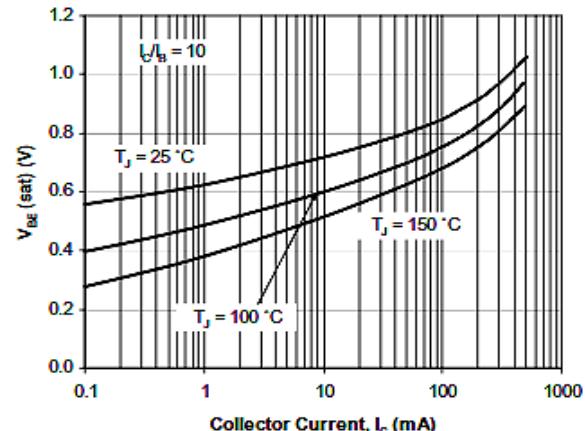
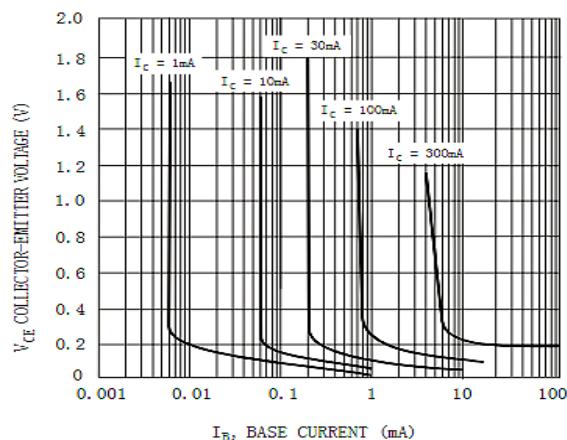

 Fig 7: Typical $V_{BE(sat)}$ vs Collector Current


Fig 8: Typical Collector Saturation Region



Typical Characteristic curves

Fig 9: Gain Bandwidth Product VS. Collector Current

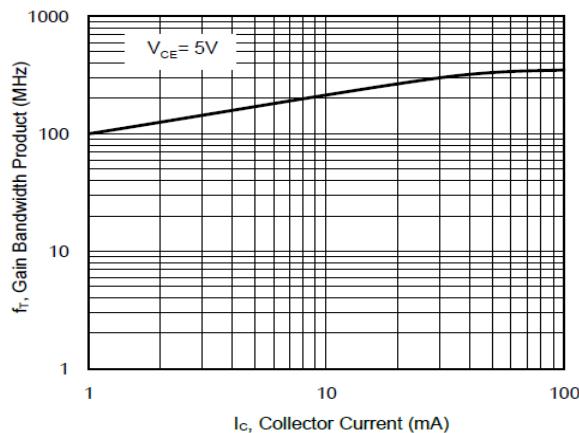


Fig 11: Frequency effects

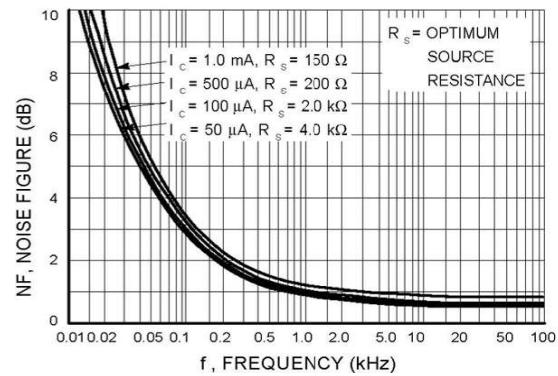


Fig 10: Source resistance Vs Noise Figure

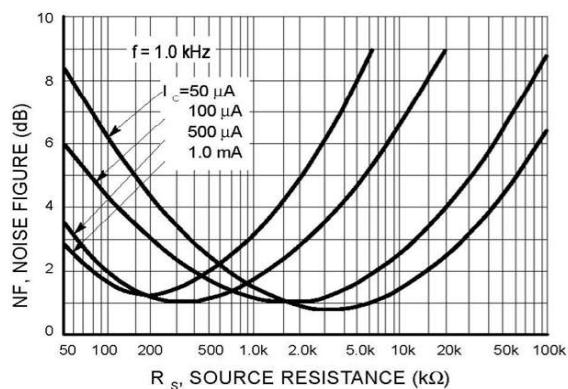
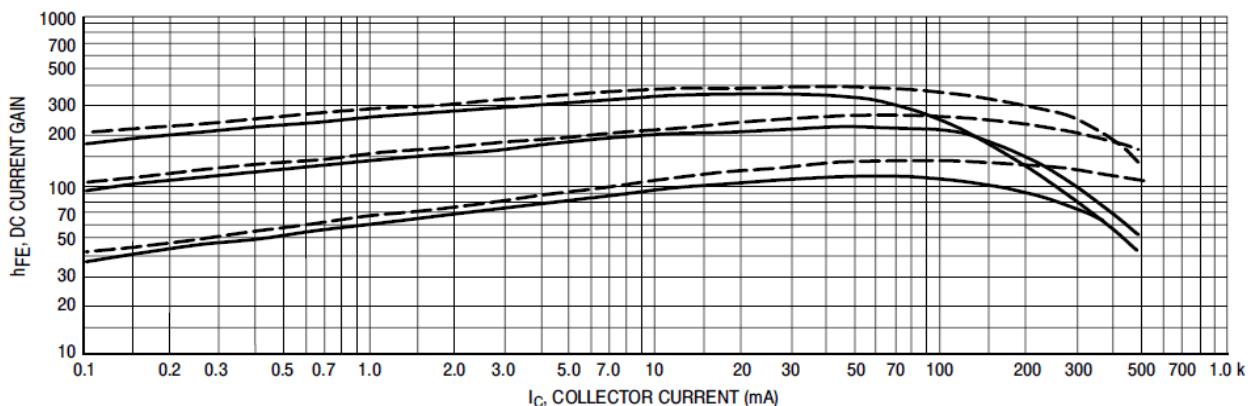


Fig 11. DC Current Gain





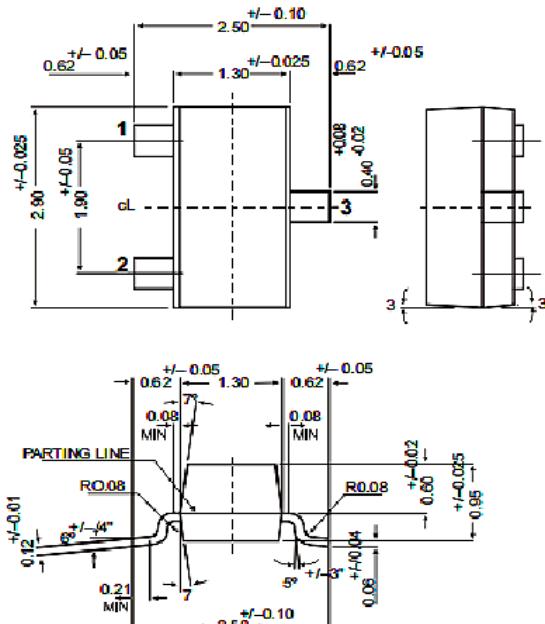
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PACKAGE DETAILS

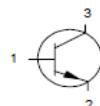
SOT-23 SMD Package



All dimensions in mm

PIN CONFIGURATION (NPN)

1. BASE
2. Emitter
3. Collector



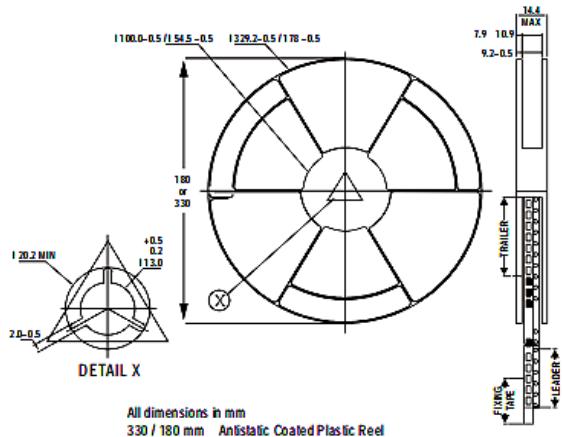
Ordering Information

Device	Ordering Part Number
CMBT2222	TCMBT2222
CMBT2222A	TCMBT2222A

CMBT2222A
Rev 4_13042022EM



Reel specifications for Packing (13"/7" reels)

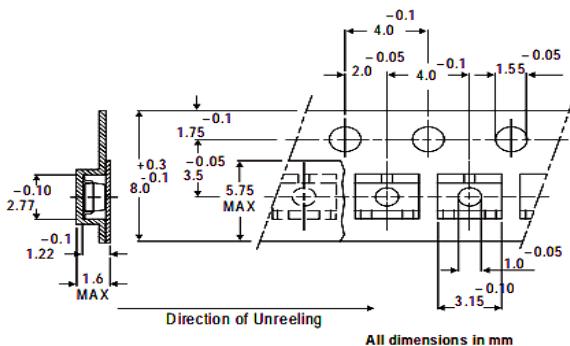


Size of Tape	8mm	8mm
Size of reel	330mm (13")	180mm (7")
No. of Device	10,000 Pcs	3,000 Pcs

NOTES:

1. The bandoier of 330mm reel contains at least 10,000 device.
2. The bandoier of 180mm reel contains at least 3,000 device.
3. No more than 0.5% missing device/reel 50 empty compartments for 330mm reel. 15 empty compartments for 180mm reel.
4. Three consecutive empty places might be found provided this gap is followed by 6 consecutive devices.
5. The carrier tape (leader) starts with at least 75 empty positions (equivalent to 330 mm). In order to fix the carrier tape a self adhesive tape of 20 to 50 mm is applied. At the end of the bandolier at least 40 empty positions (equivalent to 160 mm) are there.

Tape Specification for SOT-23 Surface Mount Device



Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
SOT-23 T&R	3K/reel	136 gm/3K pcs	3" x 7.5" x 7.5"	12.0K	17" x 15" x 13.5"	192.0K	12 kgs
	10K/reel	415 gm/10K pcs	9" x 9" x 9"	51.0K	19" x 19" x 19"	408.0K	28 kgs
			13" x 13" x 0.5"	10.0K	17" x 15" x 13.5"	300.0K	16 kgs



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Recommended Product Storage Environment for Discrete Semiconductor Devices

This storage environment assumes that the Diodes and transistors are packed properly inside the original packing supplied by CDIL.

- Temperature 5 °C to 30 °C
- Humidity between 40 to 70 %RH
- Air should be clean.
- Avoid harmful gas or dust.
- Avoid outdoor exposure or storage in areas subject to rain or water spraying .
- Avoid storage in areas subject to corrosive gas or dust. Product shall not be stored in areas exposed to direct sunlight.
- Avoid rapid change of temperature.
- Avoid condensation.
- Mechanical stress such as vibration and impact shall be avoided.
- The product shall not be placed directly on the floor.
- The product shall be stored on a plane area. They should not be turned upside down. They should not be placed against the wall.

Shelf Life of CDIL Products

The shelf life of products is the period from product manufacture to shipment to customers. The product can be unconditionally shipped within this period. The period is defined as 2 years.

If products are stored longer than the shelf life of 2 years the products shall be subjected to quality check as per CDIL quality procedure.

The products are further warranted for another one year after the date of shipment subject to the above conditions in CDIL original packing.

Floor Life of CDIL Products and MSL Level

When the products are opened from the original packing, the floor life will start.

For this, the following JEDEC table may be referred:

JEDEC MSL Level		
Level	Time	Condition
1	Unlimited	≤30 °C / 85% RH
2	1 Year	≤30 °C / 60% RH
2a	4 Weeks	≤30 °C / 60% RH
3	168 Hours	≤30 °C / 60% RH
4	72 Hours	≤30 °C / 60% RH
5	48 Hours	≤30 °C / 60% RH
5a	24 Hours	≤30 °C / 60% RH
6	Time on Label(TOL)	≤30 °C / 60% RH



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Customer Notes

Component Disposal Instructions

1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s). CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



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